

NSVBC817-16LT1G

NSVBC817-16LT1G Information





Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



NSVBC817-16LT1G Specifications

Manufacturer Part Number	NSVBC817-16LT1G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	500mA
Voltage - Collector Emitter Breakdown (Max)	45V
Vce Saturation (Max) @ Ib, Ic	700mV @ 50mA, 500mA
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 100mA, 1V
Power - Max	225mW
Frequency - Transition	100MHz
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	SOT-23-3 (TO-236)
	Report errors?

E-mail: salesdept@heisener.com

NSVBC817-16LT1G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

NSVBC817-16LT1G Payment Methods



NSVBC817-16LT1G Shipping Methods



If you have any question about NSVBC817-16LT1G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com